TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

# SM10LZ47

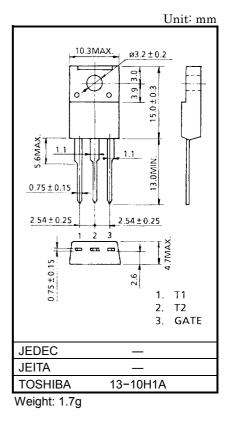
## AC POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : V<sub>DRM</sub> = 800V
- R.M.S. On–State Current : IT (RMS) = 10A
- High Commutation (dv / dt)
- : V<sub>ISOL</sub> = 1500V AC

#### **MAXIMUM RATINGS**

Isolation Voltage

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage	V <sub>DRM</sub>	800	V	
R.M.S On-State Current (Full Sine Waveform)	I <sub>T (RMS)</sub>	10	А	
Peak One Cycle Surge On-State	<b>I</b>	100 (50Hz)	A	
Current (Non-Repetitive)	ITSM	110 (60Hz)		
I <sup>2</sup> t Limit Value	l <sup>2</sup> t	50	A <sup>2</sup> s	
Critical Rate of Rise of On-State Current (Note)	di / dt	50	Α / μs	
Peak Gate Power Dissipation	P <sub>GM</sub>	5	W	
Average Gate Power Dissipation	P <sub>G (AV)</sub>	0.5	W	
Peak Gate Voltage	V <sub>FGM</sub>	10	V	
Peak Gate Current	I <sub>GM</sub>	2	А	
Junction Temperature	Tj	-40~125	°C	
Storage Temperature Range	T <sub>stg</sub>	-40~125	°C	
Isolation Voltage (AC, t = 1min.)	VISOL	1500	V	



Note: di / dt test condition  $V_{DRM} = 0.5 \times \text{Rated}, I_{TM} \le 15\text{A}, t_{dW} \ge 10\mu\text{s},$ 

 $t_{gr} \le 250$ ns,  $i_{gp} = I_{GT} \times 2.0$ 

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current	petitive Peak Off-State Current I <sub>DRM</sub> V <sub>DRM</sub> = Rated			_	—	20	μA	
Gate Trigger Voltage	I			T2 (+) , Gate (+)		_	1.5	v
	П	V <sub>GT</sub>	V <sub>D</sub> = 12V, R <sub>I</sub> = 20Ω	T2 (+) , Gate (−)		_	1.5	
	III			T2 (-) , Gate (-)	_	_	1.5	
Gate Trigger Current	I			T2 (+) , Gate (+)	_	_	30	mA
	П	I <sub>GT</sub>	V <sub>D</sub> = 12V, R <sub>I</sub> = 20Ω	T2 (+) , Gate (−)		_	30	
	III			T2 (-) , Gate (-)		_	30	
Peak On-State Voltage		V <sub>TM</sub>	I <sub>TM</sub> = 15A			_	1.5	V
Gate Non-Trigger Voltage V <sub>GD</sub> V <sub>D</sub> = Rated, Tc = 1		= 125°C	0.2	_	_	V		
Holding Current I <sub>H</sub> V <sub>D</sub> = 12V, I <sub>TM</sub>		= 1A		_	50	mA		
Thermal Resistance		R <sub>th (j−c)</sub>	Junction to Case, AC			_	3.4	°C/W
Critical Rate of Rise of Off-State Voltage d		dv / dt	V <sub>DRM</sub> = 600V, T <sub>j</sub> = 125°C Exponential Rise		_	300	_	V / µs
Critical Rate of Rise of Off-State Vo at Commutation	oltage	(dv / dt) c	$V_{DRM} = 400V, T_j = 125^{\circ}C$ (di / dt) c = - 5.5A / ms		10	_	_	V / µs

## MARKING

	NUMBER	SYMBOL		MARK
	*1	TOSHIBA PRODUCT MARK		5
	*2	TYPE	SM10LZ47	M10LZ47
	*3		arting from phabet A t Decimal Digit he Current Year )	Example 8A: January 1998 8B: February 1998 8L: December 1998

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